

Hybrid Multilevel Power Conversion System: a competitive solution for high power applications

Madhav D. Manjrekar*

Peter Steimer[#]

Thomas A. Lipo*

*Department of Electrical and Computer Engineering
University of Wisconsin – Madison
1415 Engineering Drive
Madison, WI 53706, USA

[#]ABB Industrie AG, Dept. IA, 5300 Turgi, Switzerland.

Abstract- Use of multilevel inverters is becoming popular in recent years for high power applications. Various topologies and modulation strategies have been investigated for utility and drive applications in literature. Trends in power semiconductor technology indicate a trade-off in the selection of power devices in terms of switching frequency and voltage sustaining capability. New power converter topologies permit modular realization of multilevel inverters using a hybrid approach involving Integrated Gate Commutated Thyristors (IGCT) and Insulated Gate Bipolar Transistors (IGBT) operating in synergism. This paper is devoted to the investigation of a hybrid multilevel power conversion system typically suitable for high performance, high power applications. This system designed for 4.16 kV, ≥ 100 HP load comprises of a hybrid seven-level inverter, a diode bridge rectifier and an IGBT rectifier per phase. The IGBT rectifier is used on the utility side as a real power flow regulator to the low voltage converter and as a harmonic compensator for the high voltage converter. The hybrid seven-level inverter on the load side consists of a high voltage, slow switching IGCT inverter and a low voltage, fast switching IGBT inverter. By employing different devices under different operating conditions, it is shown that one can optimize the power conversion capability of entire system. A detailed analysis of a novel hybrid modulation technique for the inverter, which incorporates stepped synthesis in conjunction with variable pulse width of the consecutive steps is included. In addition, performance of a multilevel current regulated delta modulator as applied to the single phase full bridge IGBT rectifier is discussed. Detailed computer simulations accompanied with experimental verification are presented in the paper.

I. INTRODUCTION

Multilevel power conversion has been receiving increasing attention in the past few years for high power applications [1]. Numerous topologies and modulation strategies have been introduced and studied extensively for utility and drive applications in the recent literature [2]. These converters are suitable in high voltage and high power applications due to their ability to synthesize waveforms with better harmonic spectrum and attain higher voltages with a limited maximum device rating. In the family of multilevel

inverters, topologies based on series connected H-bridges are particularly attractive because of their modularity and simplicity of control [3]. Such H-bridge multilevel inverters have also been implemented successfully in the industrial applications for high power drives [4]. A typical seven-level configuration reported in the literature is shown in Figure 1. As may be seen from this figure, this conventional seven-level inverter comprises of three H-bridge cells (referred to as “power cells”) per phase. All power cells have independent dc links of equal magnitude (V). The input transformer provides isolation to individual cells and is configured so as to obtain an eighteen pulse current waveform at the utility side. This particular system is designed for 2.3 kV drive applications and an extended eleven-level version is also reported for 4.16 kV applications [4].

Recent trends in the power semiconductor technology indicate a trade-off in the selection of power devices in terms of switching frequency and voltage sustaining capability [5]. Normally, the voltage blocking capability of faster devices such as Insulated Gate Bipolar Transistors (IGBT) and the switching speed of high voltage thyristor-based devices like Integrated Gate Commutated Thyristors (IGCT) [6] is found to be limited. With a modular H-bridge topology, realization of multilevel inverters using a hybrid approach involving IGCTs and IGBTs operating in synergism is possible [7].

This paper is devoted to the investigation of a **Hybrid Multilevel Power Conversion (HMPC)** system for medium voltage (4.16 kV), high power (≥ 100 HP) applications. A simplified schematic of the power circuit of the proposed system is shown in Figure 2. As may be observed, this system consists of one “hybrid cell” per phase. The hybrid cell comprises of a seven-level hybrid inverter [8] with dc bus voltages configured in the ratio 2:1 (2V and V) and a combination of a passive diode bridge and an active IGBT rectifier front end.

The following section presents a brief description of the hybrid multilevel inverter. Simulation and experimental results demonstrating the feasibility of this inverter are provided in Section III. Section IV describes the spectral analysis of the hybrid modulation scheme and issues of

power interaction in the hybrid approach. The operating principles of the hybrid rectifier and description of the control strategy is presented in Section V. Section VI presents simulation results confirming the efficacy of hybrid rectification. The paper concludes with a relative comparison of the proposed hybrid approach versus conventional methods adopted by the power industry.

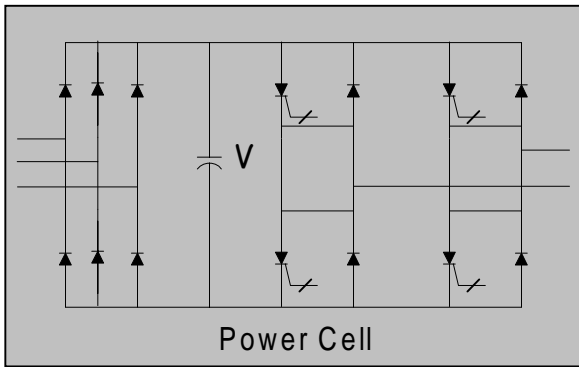
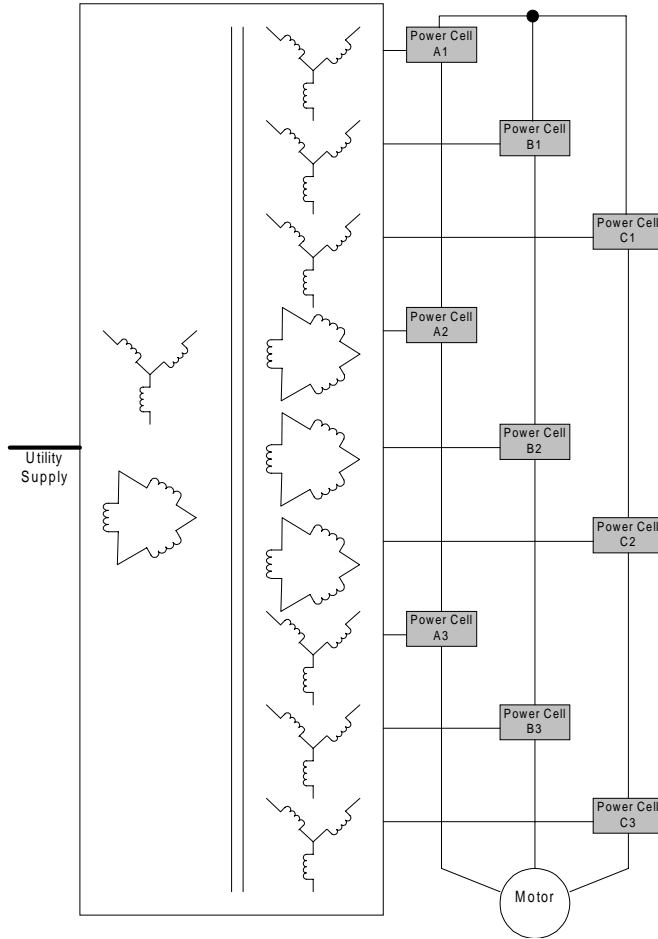


Figure 1. Simplified schematic of the conventional [4] seven-level power conversion system for 2300V drive.

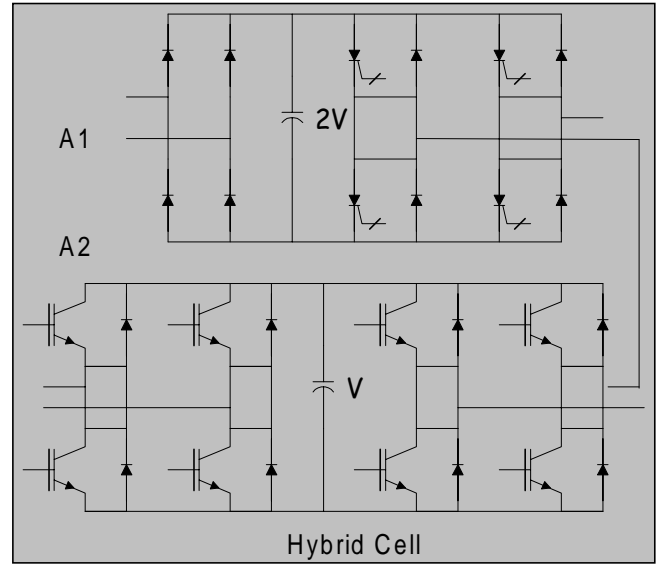
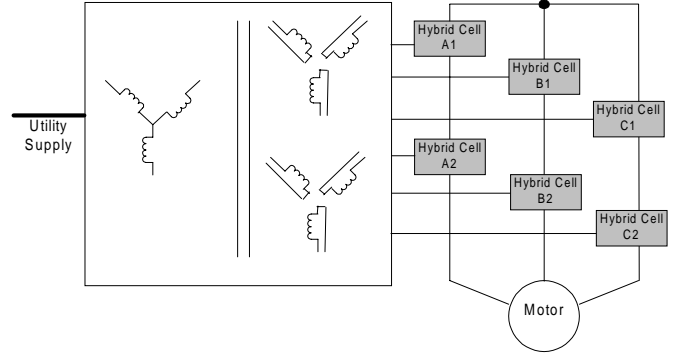


Figure 2. Simplified schematic of the proposed hybrid seven-level power conversion system for 4160V drive.

II. PRINCIPLE OF THE HYBRID MULTILEVEL INVERTER

The hybrid multilevel inverter combines an IGCT inverter with a 2.2 kV bus and an IGBT inverter with a 1.1 kV bus as shown in Figure 3. It may be easily verified that it is possible to synthesize stepped waveforms with seven voltage levels viz. -3.3 kV, -2.2 kV, -1.1 kV, 0 , 1.1 kV, 2.2 kV, 3.3 kV at the phase leg output with this topology. As shown in Figure 3, the higher voltage levels (± 2.2 kV) are synthesized using IGCT inverter while the lower voltage levels (± 1.1 kV) are synthesized using IGBT inverters. But it is well known that the switching capability of thyristor based devices is limited at higher frequencies [5]. Hence a hybrid modulation strategy which incorporates stepped synthesis in conjunction with variable pulse width of consecutive steps has been presented in [8]. Under this modulation strategy, the IGCT inverter is modulated to switch only at fundamental frequency of the inverter output while the IGBT inverter is used to switch at a higher frequency. The modulation process and the state of the inverters for various levels of command signals is summarized in Table I.

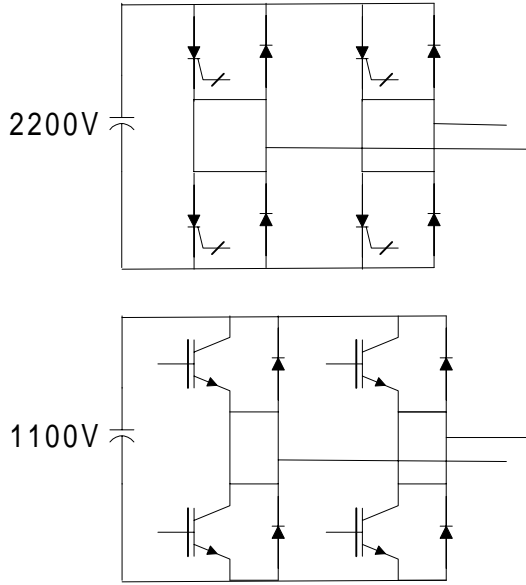


Figure 3. Simplified schematic of one leg of the hybrid multilevel inverter.

Table I. Hybrid modulation scheme

Desired output between	IGCT Inverter	IGBT Inverter
-3.3 and -2.2 kV	-2.2 kV	$0 \leftrightarrow -1.1 \text{ kV}$
-2.2 and -1.1 kV	-2.2 kV	$0 \leftrightarrow 1.1 \text{ kV}$
-1.1 and 0.0 kV	0 kV	$0 \leftrightarrow -1.1 \text{ kV}$
0.0 and 1.1 kV	0 kV	$0 \leftrightarrow 1.1 \text{ kV}$
1.1 and 2.2 kV	2.2 kV	$0 \leftrightarrow -1.1 \text{ kV}$
1.1 and 3.3 kV	2.2 kV	$0 \leftrightarrow 1.1 \text{ kV}$

$a \leftrightarrow b$: Switching between a and b

III. SIMULATION RESULTS AND EXPERIMENTAL VERIFICATION OF THE HYBRID MULTILEVEL INVERTER

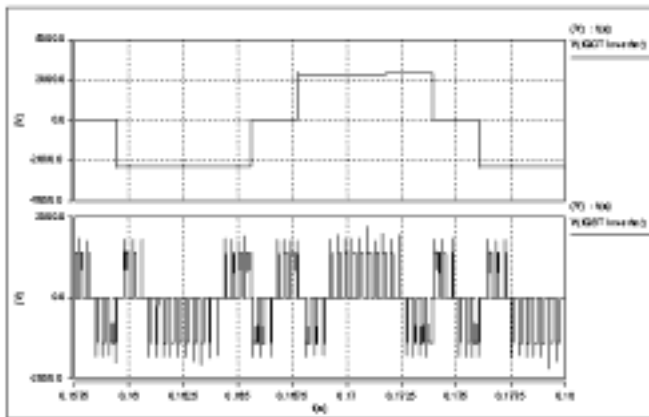


Figure 4. Simulated IGCT and IGBT inverter waveforms, $M = 0.83 \text{ p.u.}$ and $f_c = 1440 \text{ Hz.}$

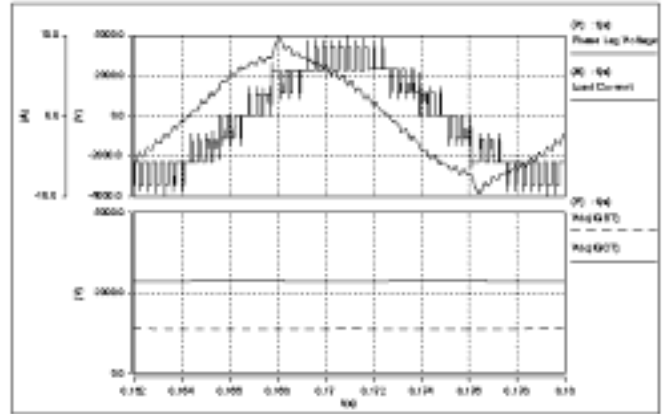


Figure 5. Simulated load and dc bus voltage waveforms, $M = 0.83 \text{ p.u.}$ and $f_c = 1440 \text{ Hz.}$

The hybrid multilevel inverter is controlled under hybrid modulation which combines a quasi-square wave synthesis of the IGCT inverter with IGBT pulse width modulation as shown in simulation results in Figure 4. The circuit simulations are done in Saber. With this hybrid topology and modulation strategy, the effective spectral response of the output depends on the IGBT switching, while the overall voltage generation is decided by the voltage ratings of the IGCTs. This is demonstrated in the phase leg voltage waveform in Figure 5. This output is obtained from a command signal with modulation depth (M) = 0.83 p.u. and switching frequency (f_c) = 1440 Hz. A single leg of the hybrid multilevel inverter as shown in Figure 3 is built in the laboratory and tested extensively. Representative waveforms at same operating point confirming the validity of hybridization are shown in Figures 6 and 7. Figure 6 shows the IGCT and IGBT inverter output voltage waveforms obtained experimentally. Figure 7 illustrates the phase leg voltage waveform, load current and the dc bus voltages.

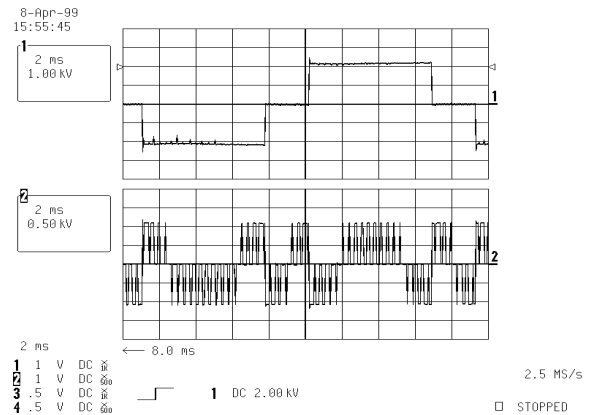


Figure 6. Experimental IGCT and IGBT inverter waveforms, $M = 0.83 \text{ p.u.}$ and $f_c = 1440 \text{ Hz.}$

Trace 1. IGCT inverter voltage 1000V/div
Trace 2. IGBT inverter voltage 500V/div

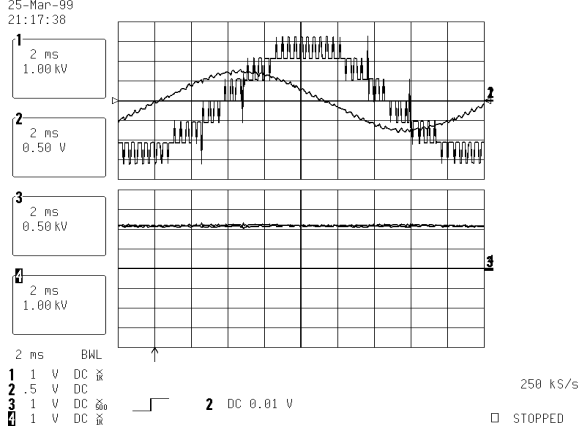


Figure 7. Experimental load and dc bus voltage waveforms, $M = 0.83$ p.u. and $f_c = 1440$ Hz.
Trace 1. Output voltage 1000V/div
Trace 2. Output current 5A/div
Trace 3. IGBT dc bus 500V/div
Trace 4. IGCT dc bus 1000V/div

IV. SPECTRAL ANALYSIS AND POWER INTERACTION IN THE HYBRID MULTILEVEL INVERTER

For spectral analysis, reference command to the hybrid inverter can be represented as

$$V_{ref} = M \cos \omega t \quad (1)$$

where M is the modulation depth which varies between $0 \leq M \leq 1$ and ω is angular frequency of the reference signal. So the IGCT inverter output and the IGBT inverter leg command are given by

$$V_{IGCT} = \sum \frac{8}{3n\pi} \sin \left\{ n \cos^{-1} \frac{1}{3M} \right\} \cos n\omega t \quad (\text{for odd } n) \quad (2)$$

$$V_{IGBT (\text{command})} = M \cos \omega t - \sum \frac{8}{3n\pi} \sin \left\{ n \cos^{-1} \frac{1}{3M} \right\} \cos n\omega t \quad (\text{for odd } n) \quad (3)$$

Now, spectrum of a naturally sampled sine-triangle PWM single phase Voltage Source Inverter (VSI) with a leg command $A \cos \omega_b t$ and carrier frequency ω_c is given in [9] as follows

$$V_{VSI} = A \cos \omega_b t + \frac{4}{\pi} \sum \sum \frac{1}{2m} J_{2n-1} A m \pi \cos \{ 2m \omega_c t + (2n-1) \omega_b t \} \quad (4)$$

(summations from $m = 1$ to ∞ and $n = -\infty$ to $+\infty$)

One can substitute Equation (3) in (4) and obtain a complete spectrum for the PWM IGBT inverter. This when added to the spectrum of the IGCT inverter (Equation (2)) gives a complete spectrum of the hybrid inverter [10]. Particularly, behavior of the individual inverters at fundamental frequency is interesting. The IGCT inverter output under hybrid modulation is plotted against the modulation depth in Figure 8. It is overlaid on a unity slope line which specifies the commanded fundamental voltage. It

may be observed that the IGCT inverter synthesizes more voltage than necessary between the modulation depths around 37% and 78%. Hence it is necessary for the IGBT inverter to cancel this excessive voltage as is illustrated in Figure 9. As may be seen from the fundamental voltage synthesized by the IGBT inverter, this inverter synthesizes negative voltage in this region of modulation depths. In terms of real power flow, which is represented by the current component that is in phase with the fundamental voltage, it appears that the IGCT inverter feeds the power into the IGBT inverter in this zone. A simple solution for this problem is to control the conduction angle of the IGCT inverter such that the fundamental voltage generated by this inverter is always less than the total commanded voltage [10]. This is depicted in Figure 10. A more sophisticated version of the solution is to solve this problem with a regenerative IGBT rectifier as will be described next.

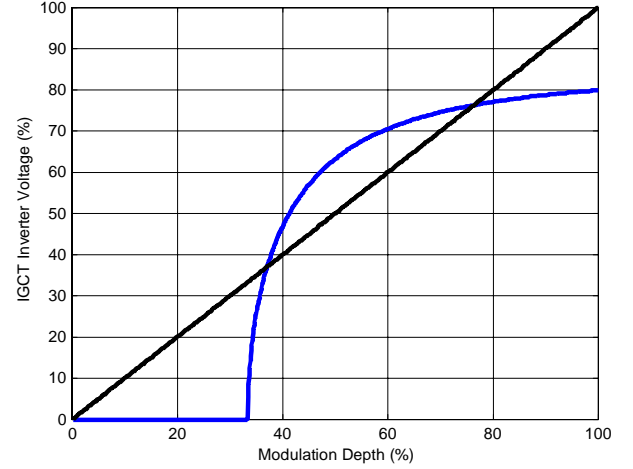


Figure 8. IGCT inverter fundamental voltage.

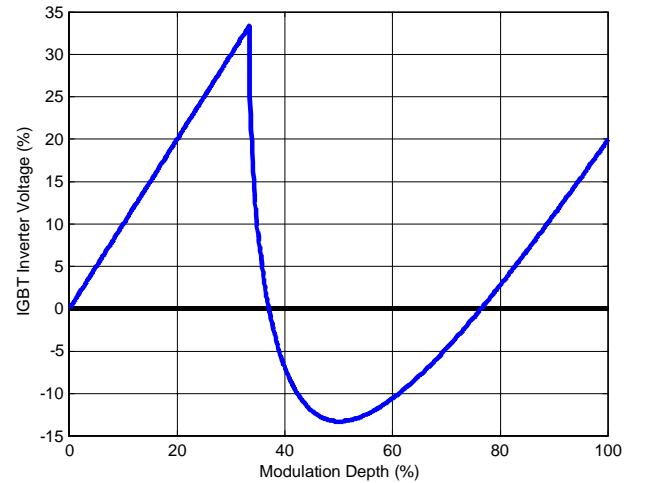


Figure 9. IGBT inverter fundamental voltage.

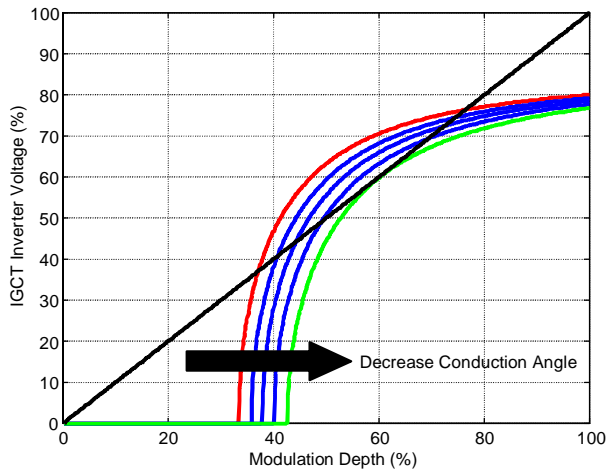


Figure 10. Conduction angle control of the IGCT inverter.

V. PRINCIPLE OF THE HYBRID MULTILEVEL RECTIFIER

It is well known that the conventional six-pulse rectifier bridges suffer from a strong harmonic interaction with the utility [11]. Therefore present day H-bridge multilevel inverters employed for feeding medium voltage loads control the utility harmonic impact by means of specially designed transformers which provide an eighteen-pulse (Figure 1) or a thirty-pulse input current [4]. Hence to simplify transformer design and interconnections combined with a low harmonic impact on the utility interface, it is proposed to use an active rectifier for the IGBT inverter along with a diode bridge front end for the IGCT inverter as shown in Figure 11. With this configuration, it is possible to use the IGBT rectifier as an active filter for the harmonics generated by the high voltage passive rectifier, as well as a real power flow controller for the low voltage converter thereby regulating its dc bus voltage irrespective of power interaction in the hybrid inverter.

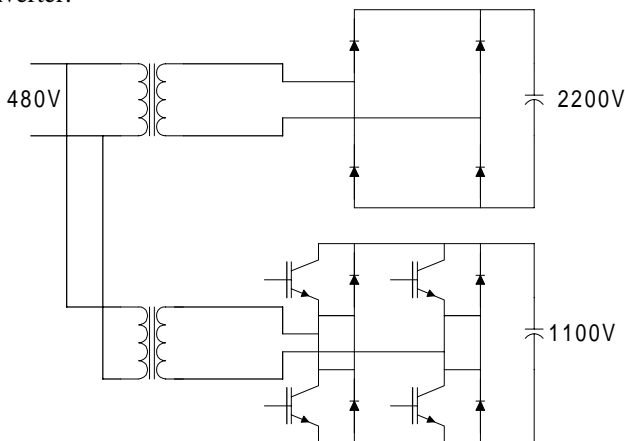


Figure 11. Simplified schematic of one leg of the hybrid multilevel rectifier.

The control action for the hybrid multilevel rectifier can be partitioned in two tasks: Reference Generation and Current Control.

Reference Generation:

It may be noted that unlike the conventional active rectifiers (where the current reference is purely fundamental [11]) or the conventional active filters (where the current reference is purely harmonic [12]), current reference in this particular case comprises of two components, fundamental and harmonic. The fundamental current reference is obtained from the dc bus voltage controller as shown in Figure 12. As may be seen from this figure, this reference generation procedure is similar to that in a conventional active rectifier [11]. The dc link in the low voltage converter is sensed and filtered and then compared against a command (1100V). The error is fed to a Proportional-Integral (PI) controller, which gives the magnitude of the current to be synthesized. This magnitude is multiplied with unit amplitude sinusoid that is phase locked with the source voltage. Thus a reference fundamental current waveform is generated that is in phase with the utility voltage.

The harmonic current reference is extracted from the current drawn by the high voltage power converter as shown in Figure 13. The harmonic extraction procedure is based on the fact that, any sinusoidal waveform can be resolved in two orthogonal components. The fundamental component in the current drawn by the diode-bridge can also be treated in the same manner. This current is sensed and is multiplied with an arbitrary orthogonal set of waveforms, in this case, unit amplitude sine and cosine waveforms. The components that are not in phase with these sine and cosine waves average out to null and can be easily separated. Whereas, the components that are in phase, form square terms which have dc values of half the amplitude. Hence these dc magnitudes are extracted and multiplied by 2 to give the projections of the fundamental component on the orthogonal axes. These projections when multiplied to the original set of orthogonal waveforms and added together give the fundamental component of the diode-bridge input current. Now one can obtain the harmonics in this current by subtracting the fundamental component from the original current. It may be noted that, an alternative means to obtain the harmonic components is to employ a filter to remove the fundamental component. However, performance of such an approach is frequency-dependent and hence not recommended [12]. The procedure described above to extract the harmonic component is time instantaneous and can be repeated for all three legs. A harmonic current reference is now generated simply by inverting this harmonic component. Thus, in effect, the IGBT rectifier also needs to draw equal and opposite harmonic current as drawn by the high voltage diode rectifier, thereby maintaining a clean interface at the utility. Simulated waveforms of harmonic extraction for one leg are shown in Figure 14. It is easily possible to extend this result to a three-phase system.

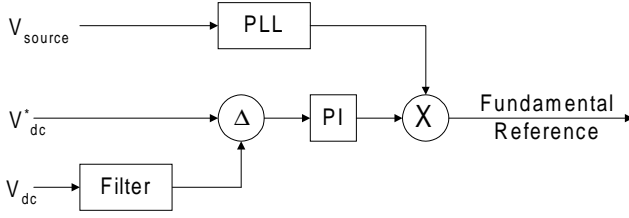


Figure 12. Simplified schematic of fundamental current reference generation.

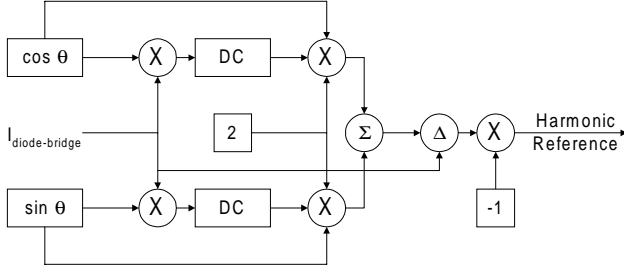


Figure 13. Simplified schematic of harmonic current reference generation.

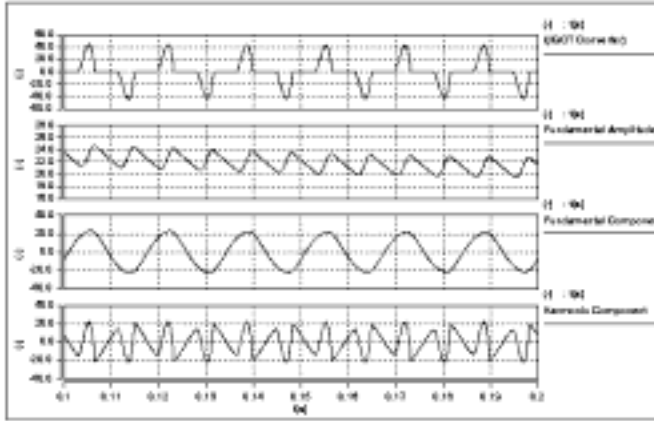


Figure 14. Simulated waveforms for harmonic component extraction from current drawn by the diode-bridge.

- Trace 1. Current drawn by the diode-bridge
- Trace 2. Amplitude of the fundamental component
- Trace 3. Waveform of the fundamental component
- Trace 4. Waveform of the harmonic component

Current Control:

Since the current references are non-sinusoidal, hysteresis current regulator is the only possible choice for current control with sufficient dynamic capability. However, this type of regulator suffers from phase interaction and low frequency current errors, especially for non-sinusoidal multiple frequency tracking [12]. Hence the current control is accomplished by a three-level delta modulator based on the family of delta modulators popular for their dynamic capability [13]. A multilevel delta modulator is realized by

replacing the two-level comparator in the conventional delta modulator by a tri-state comparator with an intermediate error-band [14]. A simplified schematic of multilevel delta modulator is shown in Figure 15. The output of the modulator may take values +1, 0 or -1 depending on the magnitude of error signal which is the difference between the reference and the actual current. This output is sampled at a constant frequency (f_s) and fed to the rectifier switches. The reference current (sum of fundamental and harmonic current references) and the control signals are shown in Figure 16.

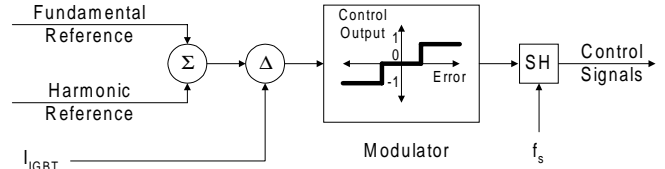


Figure 15. Simplified schematic of multilevel current regulated delta modulator.

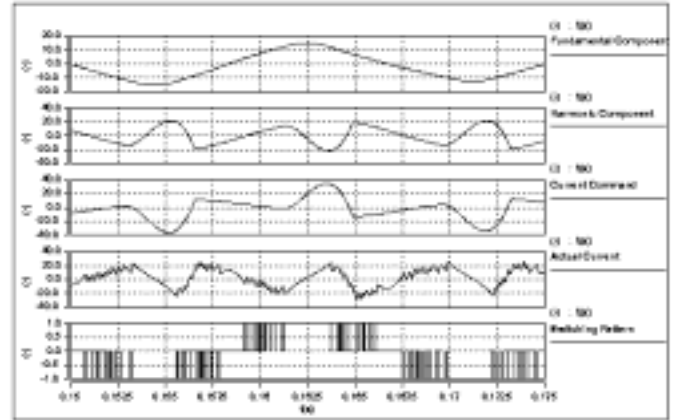


Figure 16. Simulated waveforms for reference generation and current control,

$$V_{dc(IGBT)} = 1100V \text{ and } f_s = 10 \text{ kHz.}$$

Trace 1. Fundamental current reference

Trace 2. Harmonic current reference

Trace 3. Reference current command to the IGBT rectifier

Trace 4. Actual current drawn by the IGBT rectifier

Trace 5. Control signals generated from the resultant error

VI. SIMULATION RESULTS OF THE HYBRID MULTILEVEL RECTIFIER

The hybrid multilevel rectifier is controlled with multilevel current regulated delta modulator sampled at 10 kHz. It is possible to reduce the sampling frequency further by employing programmed pulse width modulation techniques, and is currently under investigation. With the hybrid topology and control strategy, the dc link voltage in IGBT converter and input harmonic currents in IGBT converter are regulated. This is demonstrated in the current

waveforms shown in Figure 17. It may be observed that although the diode-bridge draws currents with high harmonic content, the IGBT rectifier compensates them with equal and opposite currents. This produces a near sinusoidal current at the utility interface as depicted in Figure 17. The dc link in the IGBT converter is also regulated within 5% and has been shown in Figure 5.

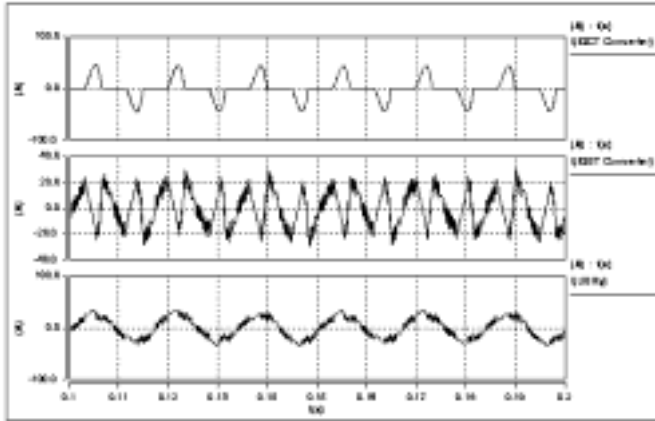


Figure 17. Simulated waveforms for currents drawn by individual rectifiers and the resultant interaction with utility, $V_{dc(IGBT)} = 1100V$ and $f_s = 10$ kHz.

Trace 1. Current drawn by the diode-bridge rectifier

Trace 2. Current drawn by the IGBT rectifier

Trace 3. Current drawn from the utility power supply

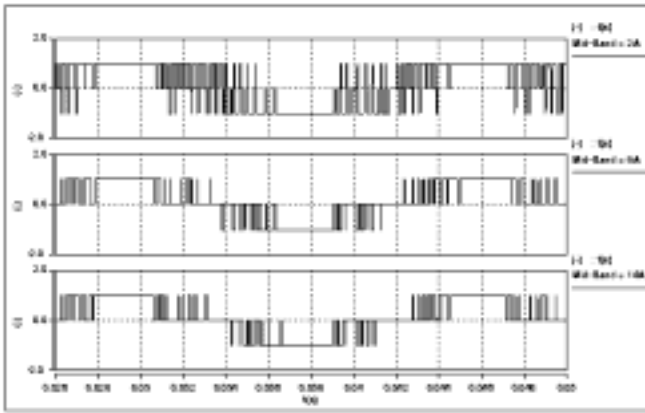


Figure 18. Simulated waveforms for control signals at various widths of mid-band.

Trace 1. Control signals for narrow error-band

Trace 2. Control signals for nominal error-band

Trace 3. Control signals for wide error-band

In addition, it may also be noted from Figure 15 that the sampling frequency (f_s) in the sample/hold and the width of the error-band in the tri-state comparator determine the spectral properties of the resulting waveforms. Intuitively, it seems that the current regulation improves as the quantization

error band approaches zero. However, decreasing the error band also reduces the occurrence of zero states, which effectively increases the ripple current. Conversely, widening the error band leads to loss of current control, thus constraining its upper limit. These effects are shown in Figures 18 and 19. It is possible to optimize the width of the error-band depending on the harmonic distortion in the utility current; however, this optimization is application specific and is not treated here.

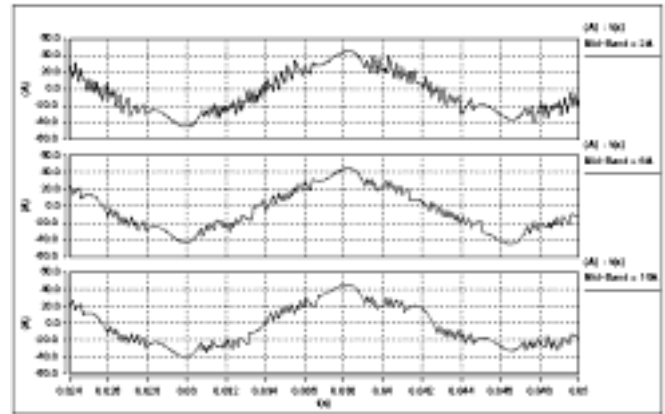


Figure 19. Simulated waveforms for resultant utility currents at various widths of mid-band.

Trace 1. Utility currents with narrow error-band

Trace 2. Utility currents with nominal error-band

Trace 3. Utility currents with wide error-band

Finally, the utility current and multilevel inverter output at $M = 0.5$ p.u. is shown in Figure 20. This operating point falls under IGBT regeneration zone (Figure 9). As explained in the spectral analysis, the IGCT inverter feeds the power to the IGBT inverter in this operating region. However, it is clear from Figure 20 that the system operation is stable and well-behaved with the proposed control strategy in this zone.

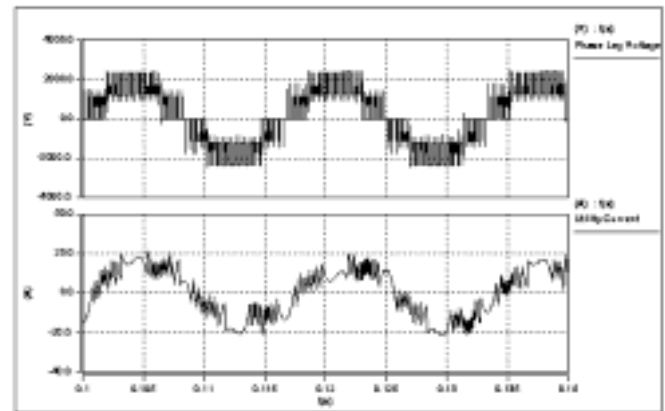


Figure 20. Simulated waveforms for multilevel inverter phase leg voltage output and utility current at $M = 0.5$ p.u.

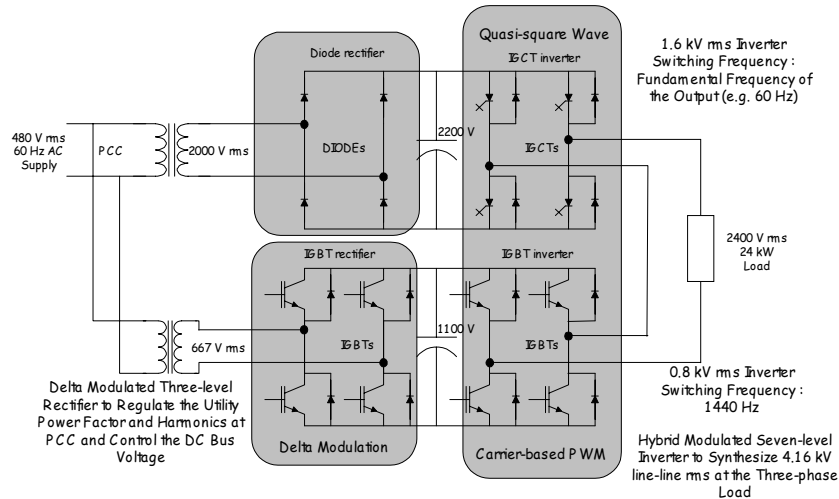


Figure 21. Illustrated power circuit schematic of one phase of the Hybrid Multilevel Power Conversion System.

VII. CONCLUSIONS

A hybrid approach in multilevel power conversion has been presented. An illustrated power circuit schematic is shown in Figure 21. It seems that the conventional H-bridge multilevel inverter is the only topology that has received a reasonable consensus along with the neutral point clamped inverter [15] in the high power community. However, the industrial implementation of such a system suffers from a principal drawback of the trade-off between harmonic interaction with the utility and complicated transformer connections. A primary advantage of the hybrid multilevel inverter is that it generates a larger number of levels with a given number of power devices or H-bridge modules. This reduces the output current distortion thereby improving the power conversion capability at the load. This fact has been verified with simulation as well as experimental results in this paper. Secondly, it employs a synergistic approach in utilizing the devices such as to obtain the advantages of both the technologies: latching devices for their high voltage blocking capability and non-latching devices for their fast switching capability. Hence, although the overall device kVA rating is same as that of a conventional H-bridge multilevel inverter, one can obtain a significant cost reduction with appropriate selection of devices. Finally, by employing a hybrid rectifier, it is possible to relieve the utility supply from harmonic interaction to a large extent. As may be seen from the simulation results presented in this paper, near sinusoidal currents can be drawn from the utility by using only one active rectifier per phase. This eliminates the need of multiple winding transformers with complicated interconnections to produce eighteen/thirty pulse current waveforms.

These attributes offer an incentive to pose the **Hybrid Multilevel Power Conversion (HMPC)** system (Figure 21) as a competitive alternative to the conventional H-bridge and even to the established neutral point clamped technology in medium voltage applications.

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